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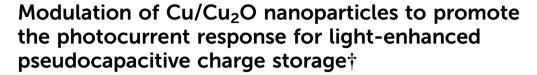


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Copper metal/copper oxide (Cu/Cu_2O) hybrid nanoparticles (HNPs) were grown on carbon cloth by an electrodeposition method. The ratio of Cu_2O in these HNPs was increased by calcination in air, remarkably promoting the photocurrent response by 150%. This $CC@Cu/Cu_2O$ photoelectrode delivered a high specific capacitance of 166 mF cm⁻² (at 5 mA cm⁻²) under light irradiation, exhibiting a light enhancement of 17.7%. In addition, a high retention of 92% can be achieved after 5000 cycles with light.

The energy shortage and environmental problems have prompted human beings to search for green and sustainable energy sources, like solar energy. 1-3 In the past few years, solar cells have been considered one of the most important technologies for direct utilization of solar energy due to their low cost, easy manufacturing, and high efficiency of solar-to-electricity conversion.4-6 However, the intermittence and variability of sunlight is the main challenge to harvest and convert solar energy efficiently. Therefore, advanced energy storage devices have been developed to connect with solar cells for conversion and storage of solar energy by directly charging the energy devices. For example, Wang et al. demonstrated a pioneering work by incorporating a dye-sensitized solar cell (DSSC) and a lithium ion battery (LIB) on the same Ti foil that had doublesided TiO2 nanotube (NTs) arrays, and this power pack can deliver a discharge capacity of 38.89 µA h under 100 µA with a light efficiency of 0.82%.8 Later, Dai et al. employed perovskite solar cell packs for direct charging of LIBs, delivering a high overall photo-electric conversion and storage efficiency of 7.80%.9 However, these power packs usually contain two separate parts, namely sunlight harvesting/conversion and electricity

Pseudocapacitive energy devices employing faradaic reactions of transition metal oxides/sulfides show similar energy storage mechanisms with battery technology, 15 but usually deliver much higher power density and longer cycling life than LIBs, 16 thus serving as an important alternative to batteries. 17 Photoactive materials, such as TiO2, Fe2O3, Co3O4, ZnO, etc. were selected as photoelectrodes to accelerate the photoinduced charge carriers. 18-22 During the charging process, the photogenerated electrons transfer to the conduction bands, which are circulated with the external electron flux, while the photogenerated holes left in the valence bands can participate in the oxidation reaction for an additional charge storage within the electrodes.²³ However, it is still a big challenge to balance the strong photosensitivity, good electroactivity and high electric conductivity within a single electrode.²⁴ Herein, pseudocapacitive electrode materials with high photoactivity and conductivity composed of Cu/Cu2O HNPs were prepared by a facile electrodeposition method against carbon cloth (CC) substrates. CC was used herein due to its high electric conductivity and good flexibility that is favorable to the electrochemical performance. The content ratio of Cu2O in this photoelectrode material (CC@Cu/Cu2O) can be increased by a subsequent calcination in air, further enhancing the photo responsive capability of this photoelectrode. Due to the strong photosensitivity and electroactivity of Cu₂O, and good high conductivity of Cu metal and CC, the typical CC@Cu/Cu2O

storage, which requires a large volume of package with external conductive connections. In recent years, bifunctional photoelectrodes have been developed to realize the *in situ* harvesting and storage of solar energy, largely enhancing the charge storage and light efficiency. ^{10–13} Jiang *et al.* reported a light-motivated SnO₂/TiO₂ heterojunction for LIBs, which enhanced the lithiation kinetics and electrochemical reversibility of both SnO₂ and TiO₂. ¹⁴ As a result, the specific capacity can be increased from 1.91 to 3.47 mA h cm⁻² at 5 mA cm⁻² for the as-reported SnO₂/TiO₂ anodes. In such bifunctional photoelectrodes, the key challenge is to optimize these two kinds of materials on an atomic scale for efficient charge separation and migration.

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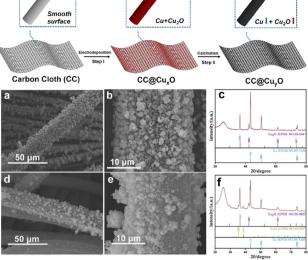


Fig. 1 Schematic illustration of the synthetic process (top image), and SEM (a), (b), (d), and (e) and XRD patterns (c) and (f) of the CC@Cu $_X$ O (a)–(c) and $CC@Cu_yO$ (d)-(f) samples.

(CC@Cu_vO) photoelectrode delivered a high specific capacitance of 166 F cm⁻² at 5 mA cm⁻² for pseudocapacitive charge storage under light irradiation, calculating a remarkable light enhancement of 17.7% compared to that obtained without light. In addition, this CC@Cu/Cu₂O photoelectrode exhibited a capacitance retention of 92% after 5000 cycles under light on conditions, suggesting a good photo and electrochemical stability.

The synthetic strategy for the CC@Cu/Cu₂O samples is presented in Fig. 1 (top image). The bare CC was firstly treated in HNO3 aqueous solution before being rinsed by DI water and dried at 70 °C for 10 h. The hydrophilicity of the CC after acid treatment is largely improved (Fig. S1, ESI†). The high surface hydrophilicity of CC can endow a good contact with charged ions in aqueous solution, which may lead to efficient and homogeneous deposition of Cu/Cu₂O species. The CC after acid treatment was then used as a growth substrate for the direct electrodeposition of Cu_xO (step I) HNPs, forming one-dimensional (1D) CC@Cu/Cu₂O hybrid structures. A subsequent calcination in air of this CC@Cu/Cu₂O leads to the oxidation of Cu metals (step II), generating more Cu₂O within the particles (Cu₂O). The morphologies of CC@Cu_rO before calcination are shown by the SEM results (Fig. 1a and b), where a rough surface against the 1D structures can be clearly observed. Compared to the bare CC, the average diameter of these 1D structures is increased to 25 µm. After annealing, the average diameter of the 1D structures is almost unchanged, while more particles have been aggregated into larger sizes (Fig. 1d and e). The particle sizes of Cu_xO were increased after calcination due to aggregation caused by re-crystallization during the heat treatment. The XRD patterns (Fig. 1c vs. Fig. 1f) show that the peak intensity of Cu (111) has reduced remarkably after calcination compared to Cu₂O (111) and CuO (111), revealing that more Cu species were transformed into Cu₂O/CuO. This also suggests that the content ratio of Cu₂O has been increased after annealing treatment, which results from the oxidation of more Cu metals during the calcination process.

To further examine the structural and elemental information of the Cu/Cu₂O HNPs, TEM and elemental mappings were conducted to compare the samples before and after calcination. Fig. 2a shows a TEM image of the Cu_rO aggregates, which were collected by ultrasonication from a substrate. The identified lattices of 0.208 and 0.246 nm from the HR-TEM image (Fig. 2b) can be assigned to the Cu (111) and Cu₂O (111), respectively.²⁵ Moreover, the elemental mapping results shown in Fig. 2c and d have demonstrated that the Cu and O elements are homogeneously interspersed, confirming the co-formation of Cu and Cu₂O during the electrodeposition. After annealing, the lattices of Cu (111) and Cu₂O (111) can be distinguished explicitly (Fig. 2e), while the lattice of CuO is absent, which should be due to a very low content within the particles. In addition, similar elemental distributions of Cu and O can be seen after annealing, verifying the uniform distribution of Cu and Cu₂O.

To examine the chemical status of copper elements in the as-prepared Cu/Cu₂O HNPs, XPS was performed and compared in Fig. 3a and b. Before calcination, only Cu⁺ can be detected in the Cu_xO sample, which corresponds to the binding energies of 952.61 eV (Cu $2p_{1/2}$) and 932.77 eV (Cu $2p_{3/2}$), ²⁶ respectively (Fig. 3a). Meanwhile, both Cu⁺ and Cu²⁺ can be detected in the Cu_vO sample after calcination, which can be seen in Fig. 3b. The binding energies of 955.5 and 936.2 eV can be assigned to Cu $2p_{1/2}$ and Cu $2p_{3/2}$ of Cu²⁺, respectively. The presence of Cu²⁺ should be due to a slight and partial oxidation of Cu₂O during the calcination at 300 °C. Moreover, the bind energies of Cu⁺ have been shifted positively to 953.5 eV (Cu 2p_{1/2}) and 934.1 eV (Cu $2p_{3/2}$), which could be caused by the oxidation of more Cu. It has been reported that there is a good photo responsive property of Cu₂O,²⁷ and thus the photocurrent responses were measured for the CC@Cu_xO and CC@Cu_yO samples. Upon light irradiation, there is a steady photocurrent of ~ 0.12 mA cm⁻² for the CC@Cu_xO sample, and the current can be increased to ~ 0.3 mA cm⁻² for the CC@Cu_vO sample (Fig. 3c), revealing a better photoactivity of the sample with higher ratio of Cu₂O and CuO. The higher photocurrent

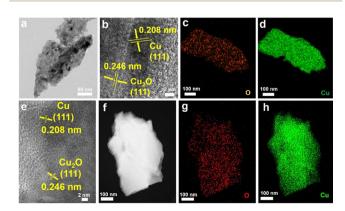


Fig. 2 TEM images (a), (b), and (e), HAADF-TEM (f), and elemental mappings (c), (d), (g), and (h) of the CC@Cu_xO (a)-(d) and CC@Cu_yO (e)-(h)

Enricing Precedure(Not)

D
Cu 2p

932.8 eV

952.6 eV

953.6 eV

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Fig. 3 XPS spectrum of Cu 2p (a) and (b) and photocurrent response (c) of the CC@Cu $_x$ O (a) and blue curve in (c) and CC@Cu $_y$ O (b) and red curve in (c) samples.

response should be mainly contributed by Cu₂O, as Cu₂O is reported to exhibit much better photocurrent response than CuO.²⁸ In addition, the content ratio of CuO is tiny in the asprepared Cu/Cu₂O particles, which played a minor role in the increase of photocurrent response.

The electrochemical surface area (ECSA) is also significant for electrochemical charge storage, and thus non-faradaic CV measurements were performed for the CC, CC@Cu_xO, and CC@Cu_yO samples, respectively (Fig. S2, ESI†). The calculated double-layer capacitances for all three samples are 0.9, 27.8, and 61.5 mF cm⁻², revealing the highest ECSA value of the CC@Cu_yO sample. A higher ECSA is considered favorable to store more charged ions at the electrode–electrolyte interface.²⁹

Next, the as-prepared CC@Cu/Cu₂O samples were then directly employed as electrodes for pseudocapacitive charge storage. Fig. 4 displays the CV, GCCD and cycling performance curves of the CC@Cu_yO sample (note: a broader voltage window of 0–0.6 V was applied for CV measurements to contain all the redox peaks). A remarkable CV areal enlargement can be seen from the comparison of the light on and off conditions at 50 mV s⁻¹ (Fig. 4a), verifying the light-enhancement of the sample. In addition, higher current densities under light on conditions were delivered than those of the respective light off conditions, which can be found from the CV curves in Fig. 4b and c, respectively. During the charge–discharge process, a longer GCCD time can be delivered

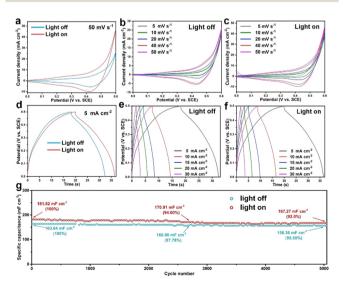


Fig. 4 CV curves (a)–(c), GCCD curves (d)–(f), and cycling performance (g) of the $CC@Cu_yO$ sample under light on and off conditions, respectively.

for the light on conditions than those for the light off conditions (Fig. 4d-f). A discharge specific capacitance of 141 mF cm⁻² can be calculated at 5 mA cm⁻² under light off conditions, and the capacitance was increased to 166 mF cm⁻² under light on conditions (Fig. 4d), revealing a light enhancement of 17.7%. While for the CC@Cu_xO sample, there are no remarkable differences for the CV and GCCD results under light off and on conditions (Fig. S3, ESI†), respectively, suggesting that the higher ratios of Cu₂O in the CC@Cu_yO sample derived from the calcination may promote the pseudocapacitive property.

As a comparison, CV and GCCD measurements were also carried out for the bare CC sample, and the results are shown in Fig. S4 (ESI†), where a negligible CV loop and GCCD time can be recoded, revealing the negligible capacitive contribution from the CC substrate. To evaluate the cycling stability of the CC@Cu_vO sample, the long-term test was carried out at 2 mA cm⁻² for 5000 cycles under light off and on conditions, respectively (Fig. 4g). Initial specific capacitances of 163.64 and 181.82 mF cm $^{-2}$ can be calculated for the light off and on conditions, respectively, while the capacitances were decreased to 156.36 and 167.27 mF cm⁻² after 5000 cycles, revealing the capacitance retentions of 95.55% and 92%, respectively. The slightly higher decay of the light on condition should be caused by possible photo corrosion of Cu2O during the cycling test. However, it should be noted that the cycling performance of the light on condition is comparable to the light off condition, which again validated a good stability of the CC@Cu_vO electrode under light irradiation.

In summary, carbon cloth-supported Cu/Cu₂O HNPs were prepared by an electrodeposition/calcination method. The ratio of Cu₂O in the sample can be increased after calcination in air, leading to a remarkably increased photocurrent response by 150%. As a result, the CC@Cu_vO sample with higher ratio of Cu₂O has exhibited a high specific capacitance of 166 mF cm⁻² under light irradiation, delivering a light enhancement of 17.7% compared to that obtained without light. In addition, a high capacitance retention of 92% can be achieved after 5000 cycles under light irradiation, revealing a good cycling stability of the sample. As a comparison, the cycling performances of the CC@CuxO sample were also evaluated under light off and on conditions (Fig. S5, ESI†), where lower specific capacitances with quick decay were obtained. This work may provide a new pathway to improve the pseudocapacitive charge storage for the typical metal oxide-based pseudocapacitive materials.

J. Xie and Y. H. Zhong carried out the experiments and analysed the collected data, W. T. Meng helped in the material characterization, T. Zhu conceived the research idea, supervised the project and wrote the manuscript, and X. B. Feng provided a discussion and revised the manuscript.

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Conflicts of interest

The authors declare no competing financial interest.

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